









SN74AHCT14Q-Q1

## SGDS023D - FEBRUARY 2002 - REVISED OCTOBER 2023

# SN74AHCT14Q-Q1 Automotive Hex Schmitt-Trigger Inverter

#### 1 Features

- Qualified for automotive applications
- EPIC™ (Enhanced-Performance Implanted CMOS) process
- Inputs are TTL-Voltage compatible
- Latch-Up performance exceeds 250 mA per JESD

# 2 Applications

- Synchronize invterted clock inputs
- Debounce a switch
- Invert a digital signal

## 3 Description

The SN74AHCT14Q-Q1 contains six independent inverters. This device performs the Boolean function  $Y = \overline{A}$ 

#### **Package Information**

	PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE (NOM)(3)
	SN74AHCT14Q-Q1	D (SOIC, 14)	8.65 mm × 6 mm	8.65 mm × 3.9 mm
		PW (TSSOP, 14)	5 mm × 6.4 mm	5 mm × 4.4 mm
		BQA (WQFN, 14)	3 mm × 2.5 mm	3 mm × 2.5 mm

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable
- The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Inverter (Positive Logic)



## **Table of Contents**

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# **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Cr	hanges from Revision C (June 2023) to Revision D (October 2023)	Pag	
•	Updated RθJA values: PW = 113 to 147.7, all values in °C/W		
•	Added Application and Implementation section	8	
Cr	hanges from Revision B (May 2023) to Revision C (June 2023)	Page	
•	Added the Applications section		
•	Updated the Package Information table to include package leads and body size	······································	

Product Folder Links: SN74AHCT14Q-Q1



# **5 Pin Configuration and Functions**

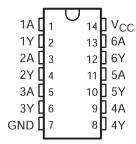


Figure 5-1. D or PW Package, 14-Pin SOIC or TSSOP (Top View)

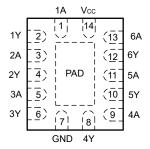


Figure 5-2. BQA Package, 14-Pin WQFN (Top View)

PIN NAME NO.		TVDE	DECORPORTION
		TYPE1	DESCRIPTION
1A	1	I	Input 1A
1Y	2	0	Output 1Y
2A	3	1	Input 2A
2Y	4	0	Output 2Y
3A	5	Į	Input 3A
3Y	6	0	Output 3Y
4Y	8	0	Output 4Y
4A	9	Ţ	Input 4A
5Y	10	0	Output 5Y
5A	11	I	Input 5A
6Y	12	0	Output 6Y
6A	13	Į.	Input 6A
GND	7	_	Ground Pin
NC	_	_	No Connection
V <sub>CC</sub>	14	_	Power Pin
Thermal Pad <sup>1</sup>	,	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.

(1) For BQA package only.



## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
V <sub>I</sub> 1	Input voltage range		-0.5	7	V
V <sub>O</sub> <sup>1</sup>	Output voltage range		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	(V <sub>I</sub> < 0)		-20	mA
I <sub>OK</sub>	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
V	V <sub>(ESD)</sub> Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
V <sub>(ESD)</sub>		Charged device model (CDM), per AEC Q100-011	±200	V

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

(over recommended operating free-air temperature range (unless otherwise noted)<sup>1</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5.5	V
VI	Input voltage	0	5.5	V
Vo	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-8	mA
I <sub>OL</sub>	Low-level output current		8	mA
T <sub>A</sub>	Operating free-air temperature	-40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## **6.4 Thermal Information**

		S	N74AHCT14Q-C	<b>)</b> 1		
	THERMAL METRIC(1)	THERMAL METRIC <sup>(1)</sup> D  PW  BQA				
			14 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	147.7	88.3	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

Product Folder Links: SN74AHCT14Q-Q1

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### 6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		T <sub>A</sub> = 25°C			MINI		LINUT	
PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	UNIT	
V <sub>T+</sub> Positive-going		4.5 V	0.9		1.9	0.9	1.9	V	
input threshold voltage  V <sub>T</sub> . Negative-going input threshold voltage $\Delta V_T$ Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )  V <sub>OH</sub> V <sub>OL</sub> I <sub>I</sub>		5.5 V	1		2.1	1	2.1	V	
V <sub>T-</sub> Negative-going		4.5 V	0.5		1.5	0.5	1.5	V	
input threshold voltage		5.5 V	0.6	-	1.7	0.6	1.7	V	
ΔV <sub>T</sub> Hysteresis (V <sub>T+</sub> -		4.5 V	0.4		1.4	0.4	1.4	V	
V <sub>T-</sub> )		5.5 V	0.4		1.5	0.4	1.5	V	
V	I <sub>OH</sub> = -50 μA	4.5 V	4.4	4.5		4.4		V	
VOH	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		V	
V	I <sub>OL</sub> = 50 μA	4.5 V		-	0.1		0.1		
VOL	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44	V	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ	
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20	μA	
ΔI <sub>CC</sub> (1)	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND	5.5 V			1.35		1.5	mA	
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		2	10			pF	

<sup>(1)</sup> This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

## **6.6 Switching Characteristics**

over recommended operating free-air temperature range  $V_{CC}$  = 5 V  $\pm$  0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	TO (OUTBUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C			MIN	MAX	UNIT	
PARAMETER	(INPUT)	10 (001701)	LOAD CAPACITANCE	MIN	TYP	MAX		IVIAA	UNII	
t <sub>PLH</sub>	Α	^	V	C <sub>I</sub> = 15 pF		4	7	1	8	ns
t <sub>PHL</sub>		T I	OL - 13 pr		4	7	1	8		
t <sub>PLH</sub>	А	V	C <sub>1</sub> = 50 pF		5.5	8	1	9	20	
t <sub>PHL</sub>		ľ	CL = 50 pr		5.5	8	1	9	ns	

#### 6.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$ 

	PARAMETER	MIN	TYP	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.9		V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.7		V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		4.3		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.1			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.5	V

<sup>(1)</sup> Characteristics are for surface-mount packages only.

## 6.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$ 

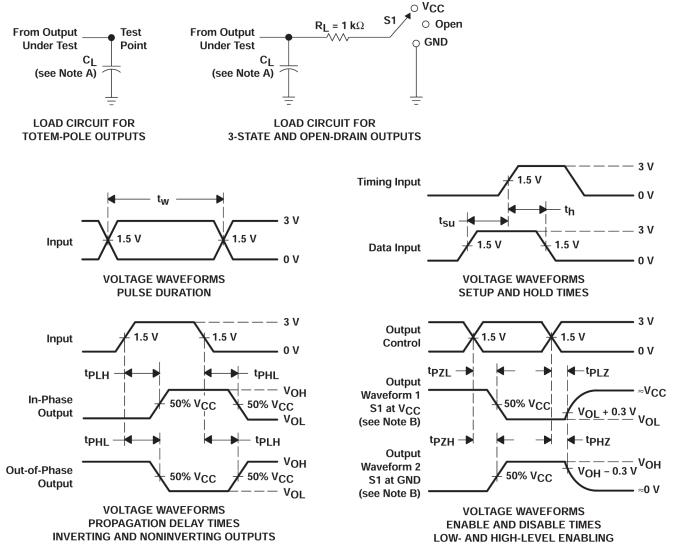
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load, f = 1 MHz	12	pF

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#### 7 Parameter Measurement Information



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 3$  ns,  $t_f \leq 3$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 7-1. Load Circuit and Voltage Waveforms

TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND
Open Drain	V <sub>CC</sub>

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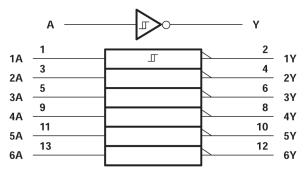


## **8 Detailed Description**

## 8.1 Overview

Each circuit functions as an independent inverter, but because of the Schmitt action, the inverters have different input threshold levels for positive-going  $(V_{T+})$  and for negative-going  $(V_{T-})$  signals.

## 8.2 Functional Block Diagram



The † symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Figure 8-1. Logic Diagram, Each Inverter (Positive Logic)

#### 8.3 Device Functional Modes

**Table 8-1. Function Table (Each Inverter)** 

INPUT	OUTPUT				
A	Y				
Н	L				
L	Н				

## 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Typical Application

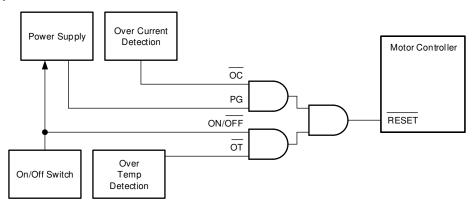


Figure 9-1. Typical Application Block Diagram

#### 9.2 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

### 9.3 Layout

## 9.3.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V<sub>CC</sub>, whichever makes more sense for the logic function or is more convenient.

Product Folder Links: SN74AHCT14Q-Q1



#### 9.3.2 Layout Example

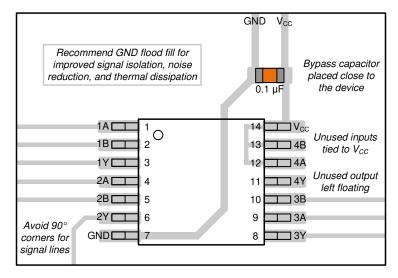


Figure 9-2. Example Layout for the SN74AHCT14Q-Q1

# 10 Device and Documentation Support

### 10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

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#### 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHCT14QDRG4Q1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT14Q	Samples
SN74AHCT14QDRQ1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT14Q	Samples
SN74AHCT14QPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB14Q	Samples
SN74AHCT14QPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB14Q	Samples
SN74AHCT14QWBQARQ1	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHT14Q	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



# PACKAGE OPTION ADDENDUM

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# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT14QPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT14QPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT14QWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1



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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT14QPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHCT14QPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHCT14QWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

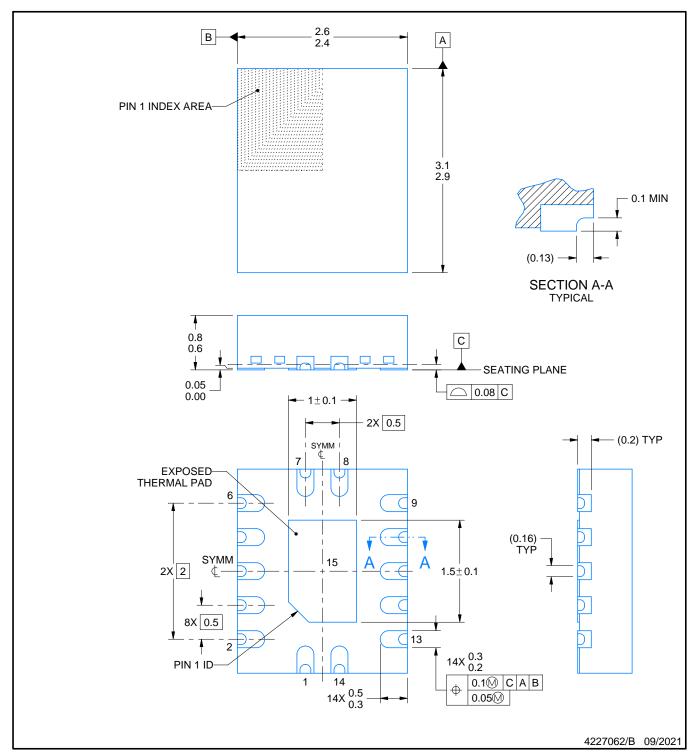
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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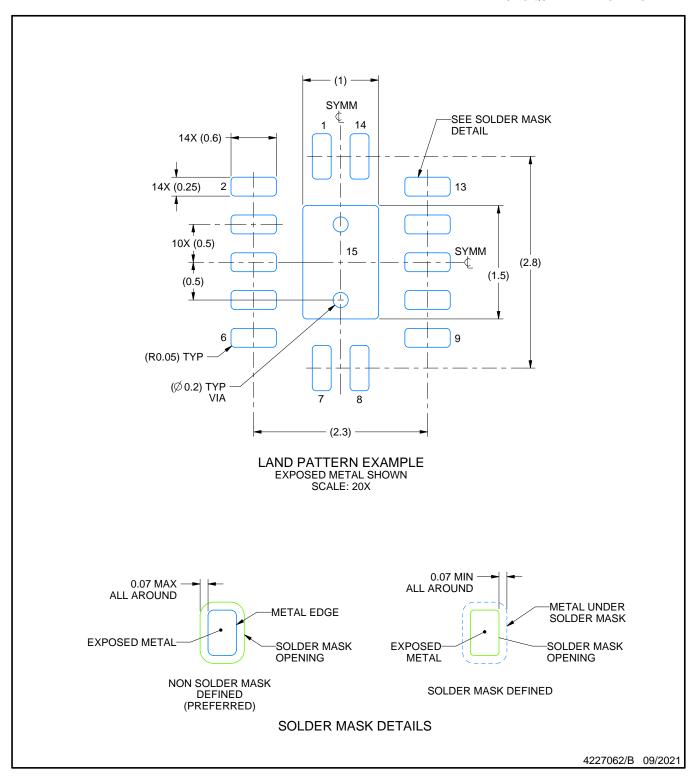
PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

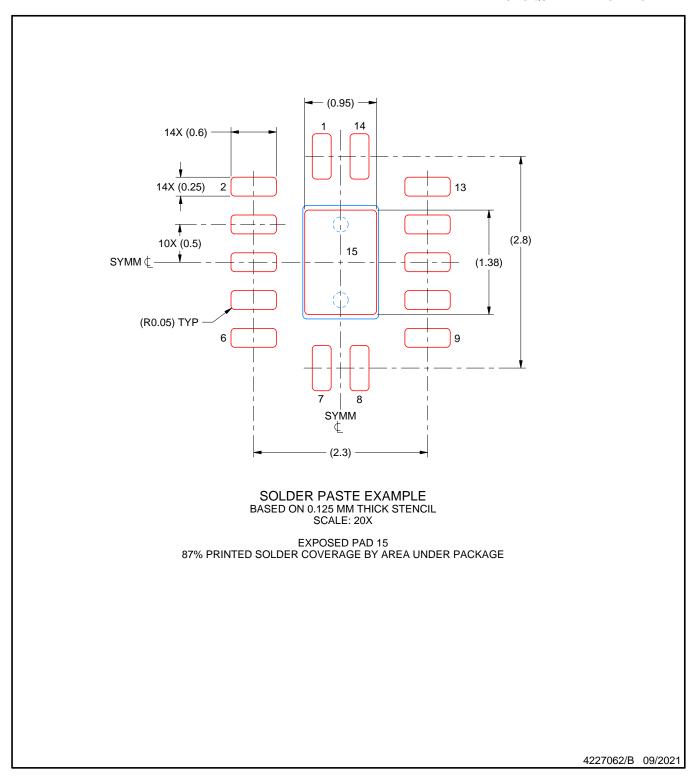


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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